

Superconductor-insulator transition in disordered FeSe thin films

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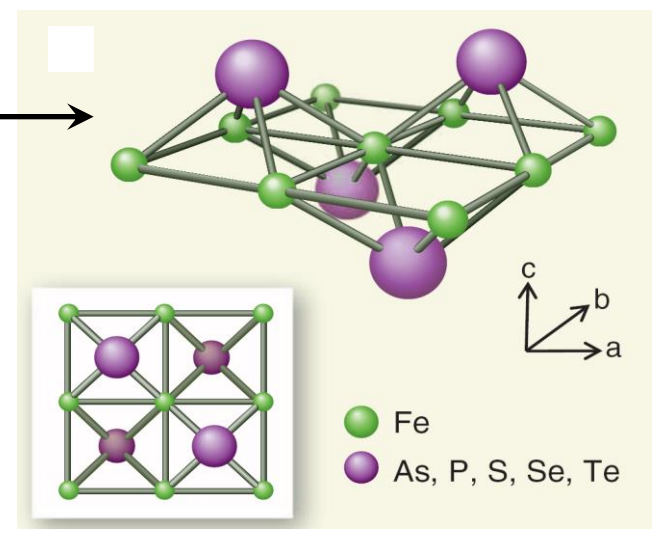
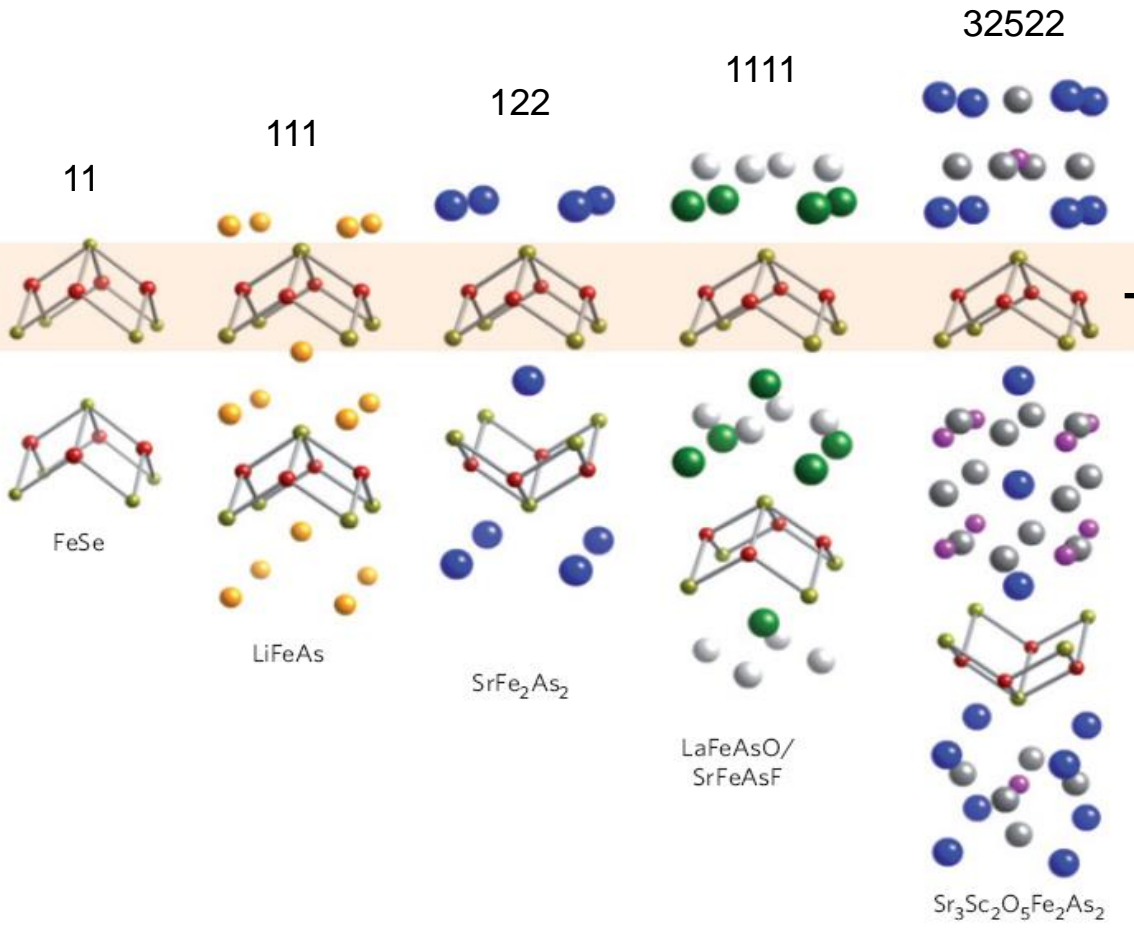
Thin Films and Interfaces

- overview of iron-based superconductors
- FeSe thin films: preparation and properties
- ordered FeSe thin films: excess conductivity and BKT transition
- disordered FeSe thin films: superconducting and insulating phases, superconductor-insulator transition
- disordered FeSe thin films in a magnetic field
- summary

Material classes of superconducting FePn / Ch

- **11** $\text{FeTe}_{1-x}\text{Se}_x$ $T_c = 15\text{K}$ for $x = 0.5$ and $T_c = 8\text{K}$ for $x = 1$
- **122*** $\text{A}_{1-x}\text{Fe}_{2-y}\text{Se}_2$ $T_c \approx 32\text{K}$ ($\text{A} = \text{K}, \text{Rb}, \text{Cs}, (\text{TI}, \text{K}), (\text{TI}, \text{Rb})$)
- **122** BaFe_2As_2 $T_c = 38\text{K}$ in $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$
- **111** LiFeAs $T_c = 18\text{K}$
- **1111** $\text{ReFeAsO}_{1-x}\text{F}_x$ $T_c = 25 - 56\text{K}$
- **21311** $\text{Sr}_2\text{VO}_3\text{FeAs}$ $T_c = 37\text{K}$ "(n+1)n(3n-1)22"

Unit cells and structural motif

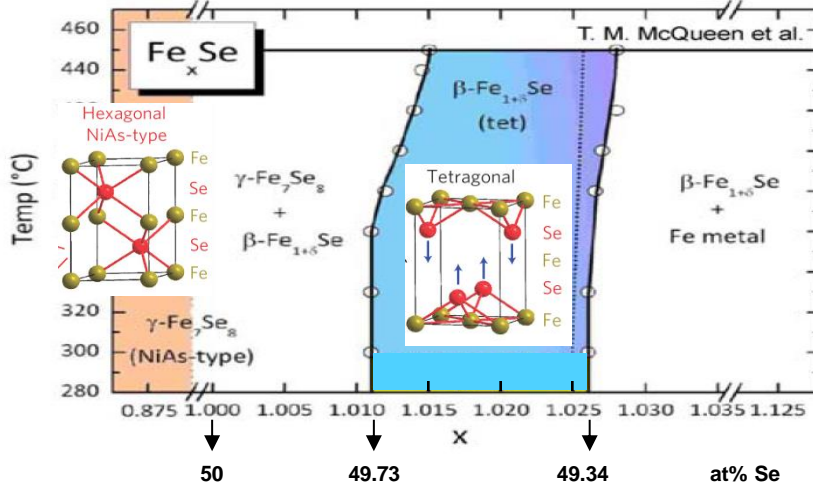


J. Paglione, R.L. Greene, Nature phys. **6**, 645 (2010)

F. Wang, D.-H. Lee, Science **332**, 200 (2011)

β - FeSe

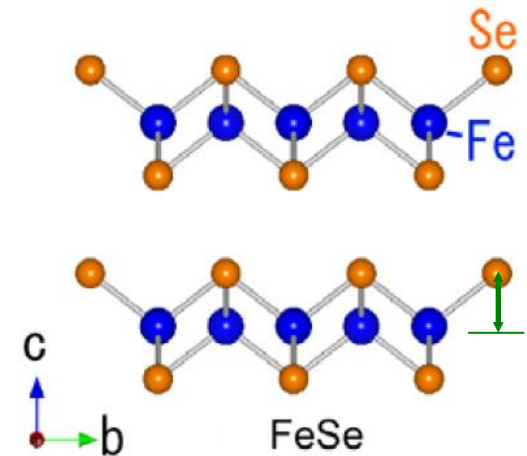
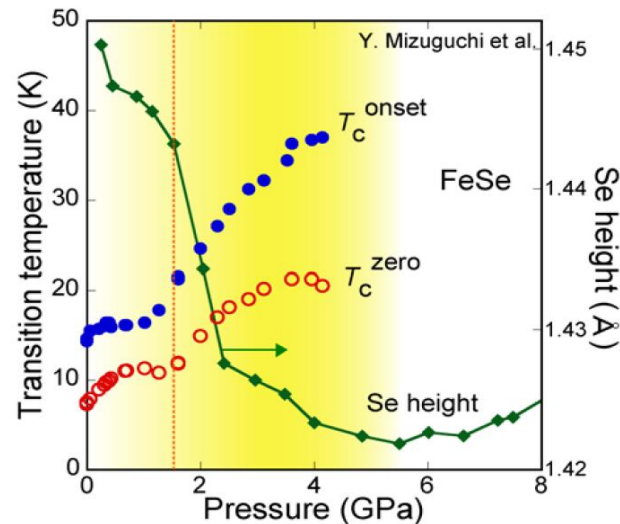
T.M. McQueen *et al.*, Phys. Rev. B **79**, 014522 (2009)



- concentration range of the β -phase very small
- tetragonal phase turns to orthorhombic below 90 K
- structural transition not accompanied by magnetic ordering
- superconductivity sensitive to composition

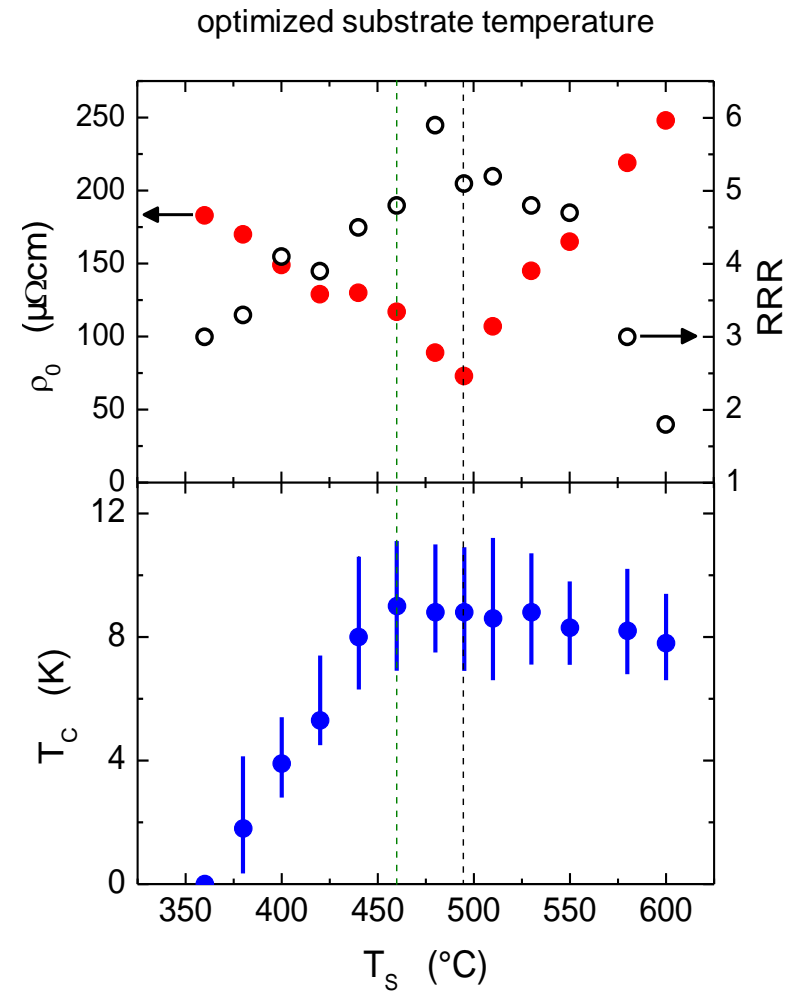
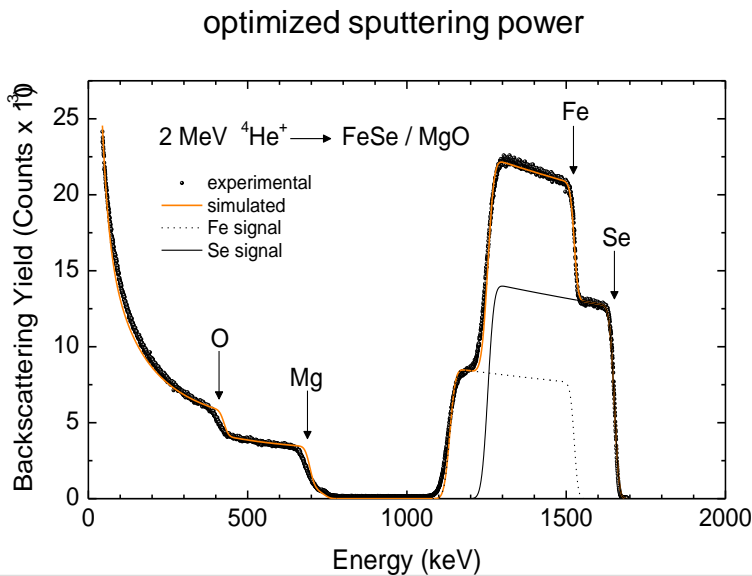
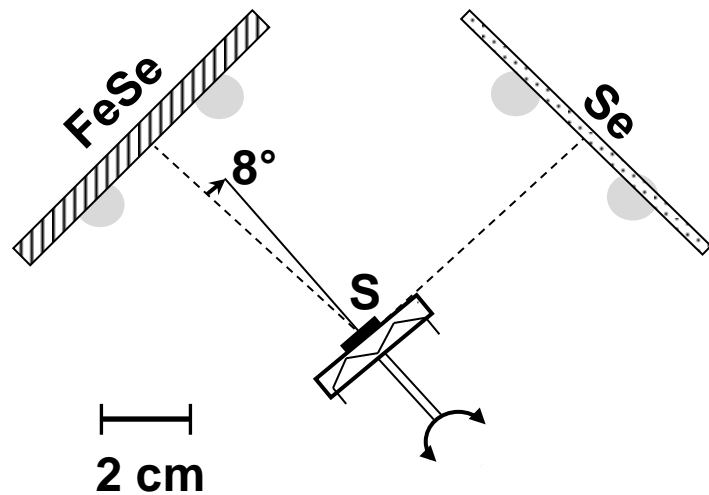
Pressure effect

- largest among Fe Pn/Ch
- T_c increase to 37 K at 4 GPa
- connected with decreasing Se height
- superconductivity sensitive to structure



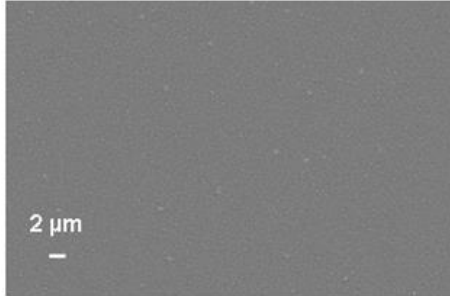
Y. Mizuguchi, Y. Takano, J. Phys. Soc. Jpn. **79**, 102001 (2010)

FeSe thin films: deposition and optimization

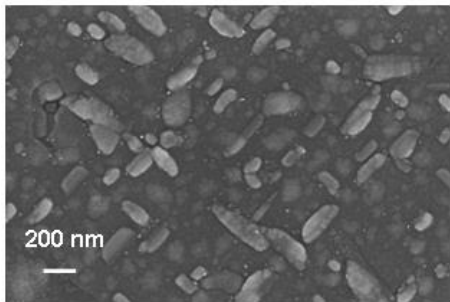


Surface and orientation

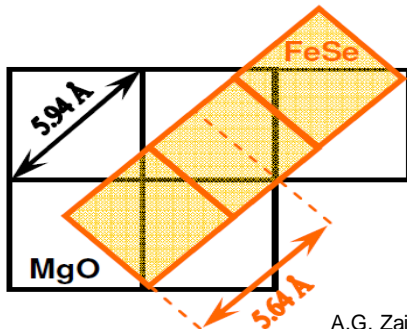
SEM



- 500 nm thick film
- smooth
- free of precipitates

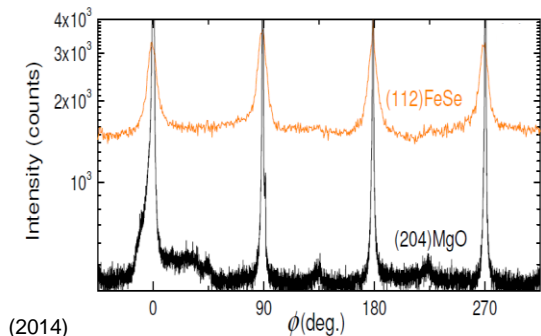
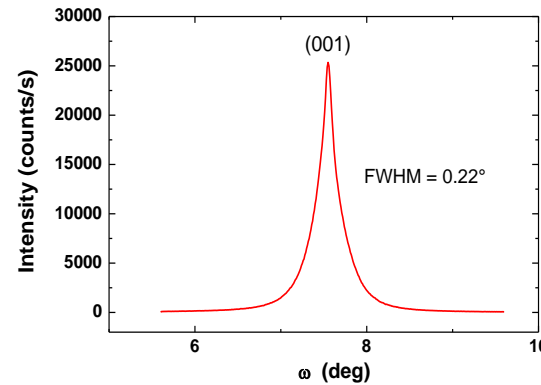
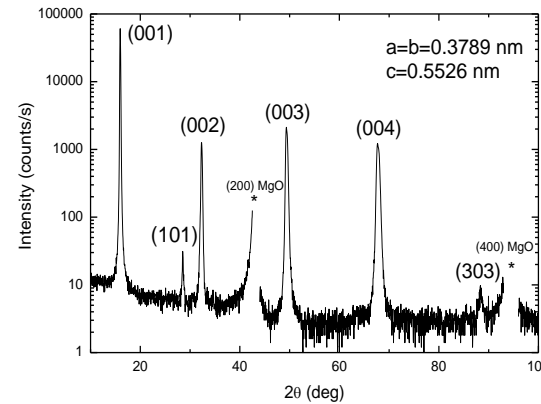


- aligned grains
- rectangular shape
- sizes 100 to 400 nm



- lattice mismatch minimized to 5%

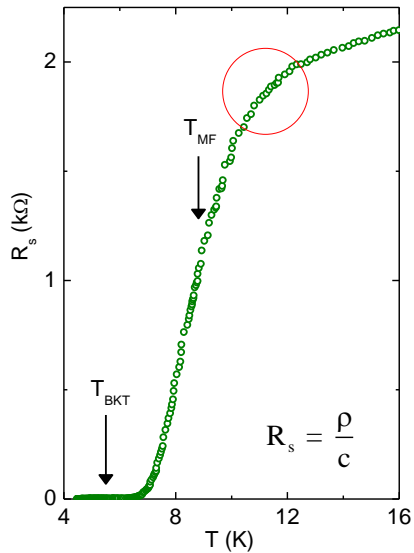
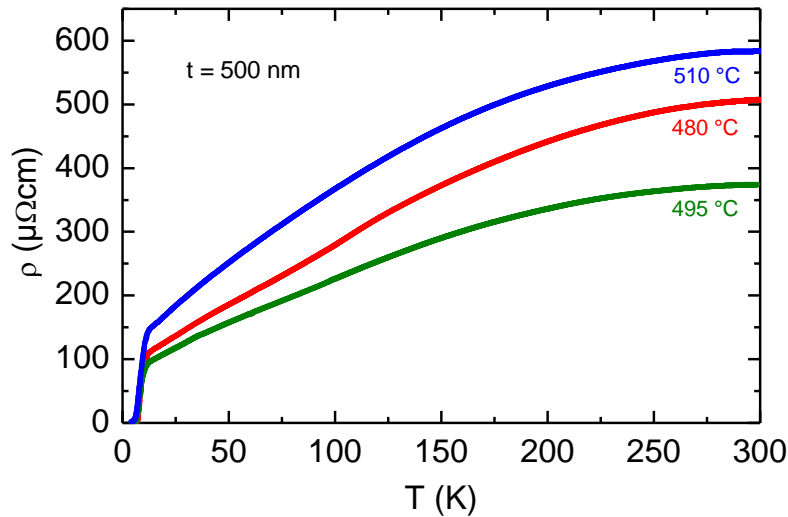
A.G. Zaitsev *et al.*, J. Phys. Conf. Ser. **507**, 012054 (2014)



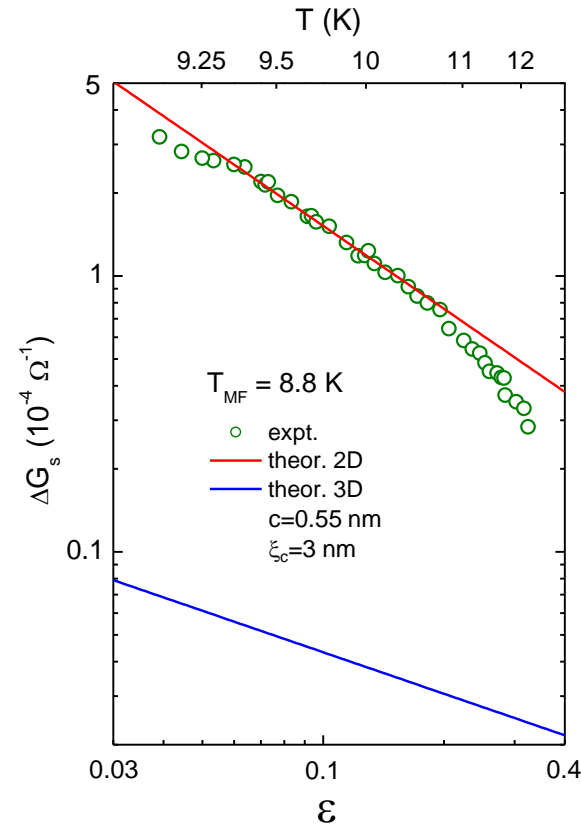
XRD

- (00l) Bragg reflections
- [001] FeSe || [001] MgO
- $a_{\text{film}} > a_{\text{bulk}}$
- small value of FWHM
- good growth quality
- fourfold rotational symmetry
- [100] FeSe || [110] MgO

Excess conductivity



- linear at low T
- parabolic with negative curvature at high T
- rounding of the transition



Excess sheet conductance per Fe-Se layer:

$$\Delta G_s = G_s - G_s^n$$

$$G_s = 1/R_s$$

$$G_s^n = (a + bT)^{-1}$$

2D Aslamazov-Larkin theory:

$$\Delta G_s = \frac{e^2}{16\hbar} \times \frac{1}{\varepsilon}$$

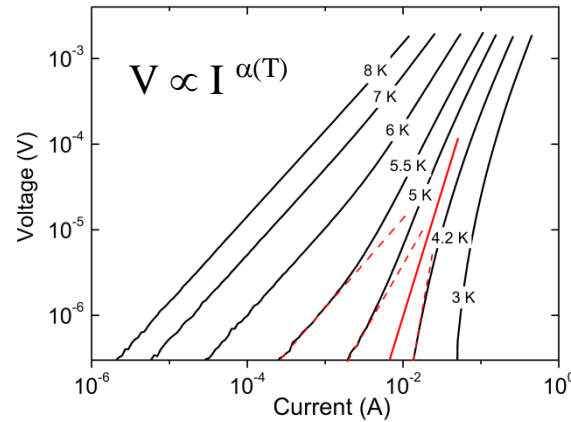
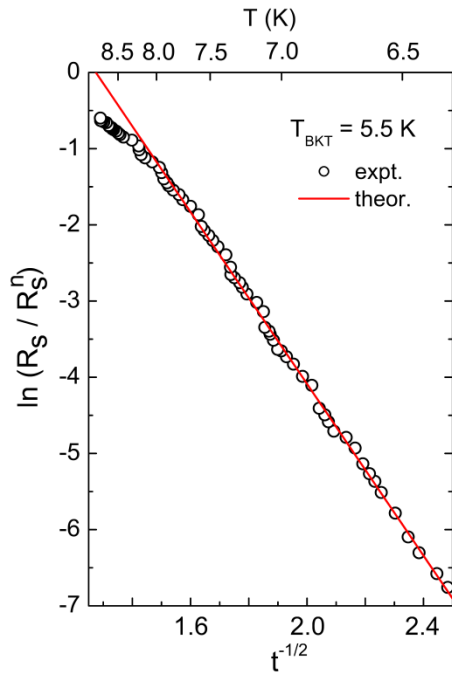
$$\frac{e^2}{16\hbar} = 1.52 \times 10^{-5} \Omega^{-1}$$

$$\varepsilon = \ln \frac{T}{T_{MF}} \approx \frac{T - T_{MF}}{T_{MF}}$$

L.G. Aslamazov, A.I. Larkin
Phys. Lett. A **26**, 238 (1968)

- 2D character of the superconducting fluctuations

BKT transition and G_i



2D Ginzburg - Levanyuk number G_i :

$$T_{\text{BKT}} = 5.5 \text{ K} \quad T_{\text{MF}} = 8.8 \text{ K} \rightarrow G_i = 5 \times 10^{-2}$$

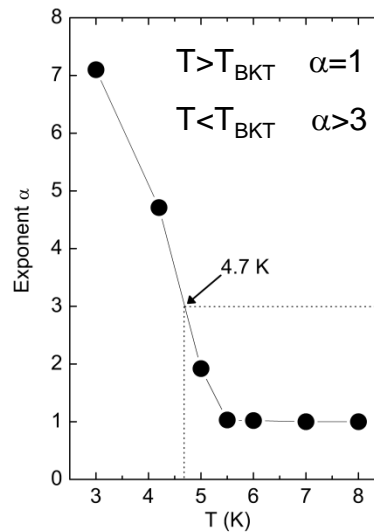
A. Larkin, A. Varlamov
Theory of Fluctuations in Superconductors
 N.Y.: Oxford University Press (2005)

- comparable to $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$
- large m and low n_s favor large G_i

B.I. Halperin, D.R. Nelson, J. Low Temp. Phys. **36**, 599 (1979)

$$\ln \frac{R_s(T)}{R_s^n(T)} = a - bt^{-1/2}$$

$$t = \frac{T}{T_{\text{BKT}}} - 1$$



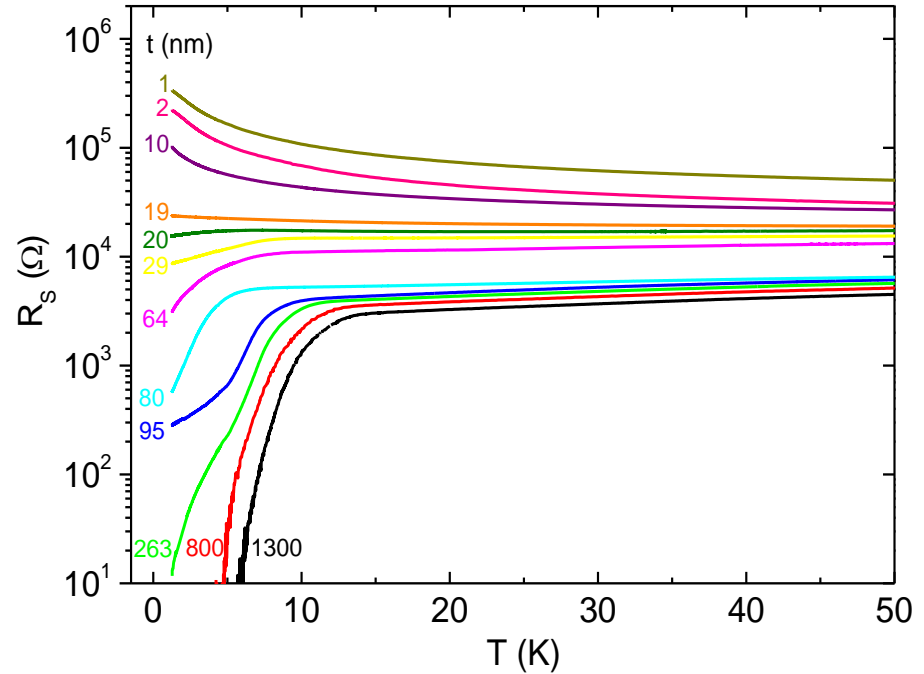
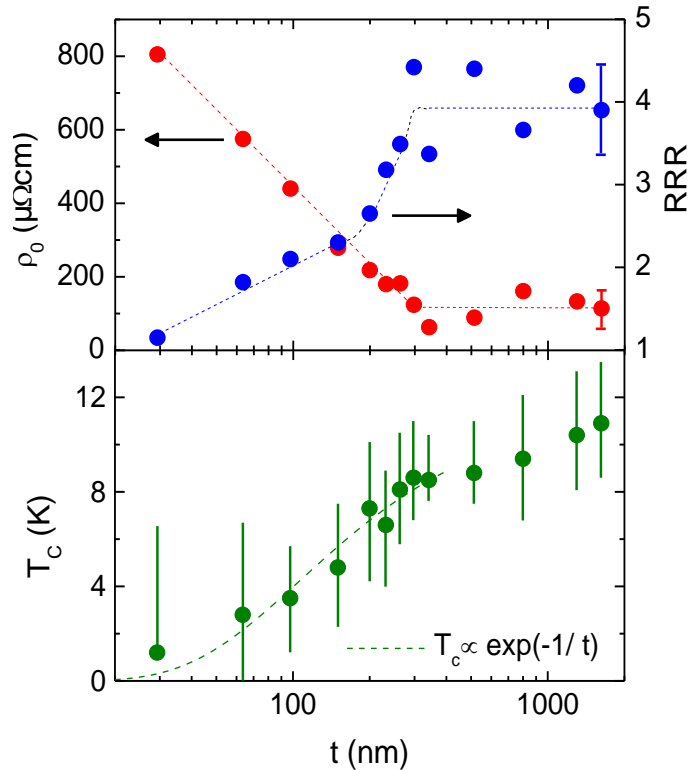
jump in α to 3 at $T_{\text{BKT}} \approx 4.7 \text{ K}$

- 2D superconducting fluctuations important in the layered FeSe compound

V.L. Berezinskii, Sov. Phys. JETP **34**, 610 (1972)

J.M. Kosterlitz, D.J. Thouless, J. Phys. C **6**, 1181 (1973)

High sensitivity to disorder



Thickness threshold at 300 nm

- bulklike features for $t > 300$ nm
- increase of ρ_0
- decrease of RRR
- decrease of T_c with decreasing $t < 300$ nm

Fanlike set of curves

20 nm $< t < 300$ nm

- $R_s(1.2\text{K}) \neq 0$
- $R_s(0) \neq 0$

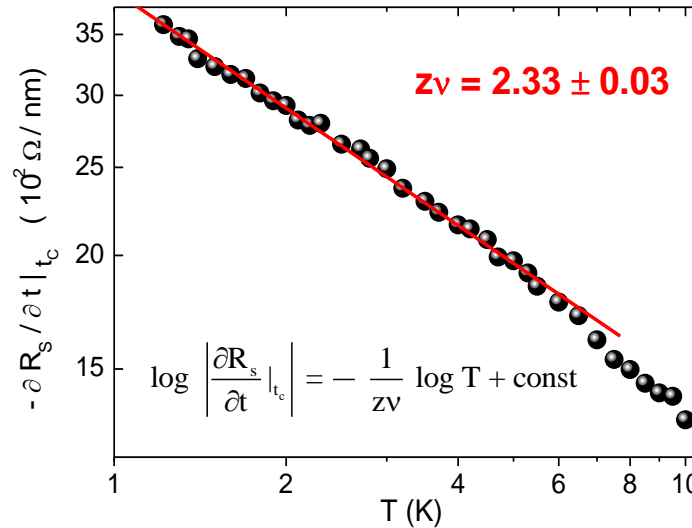
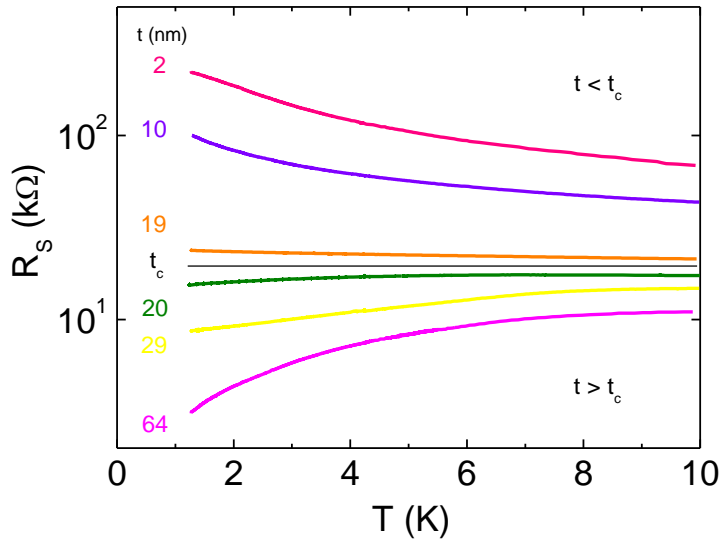
19 nm $< t < 20$ nm

- **horizontal separatrix indicating SIT**

$t < 19$ nm

- $\partial R_s(T,t)/\partial T < 0$

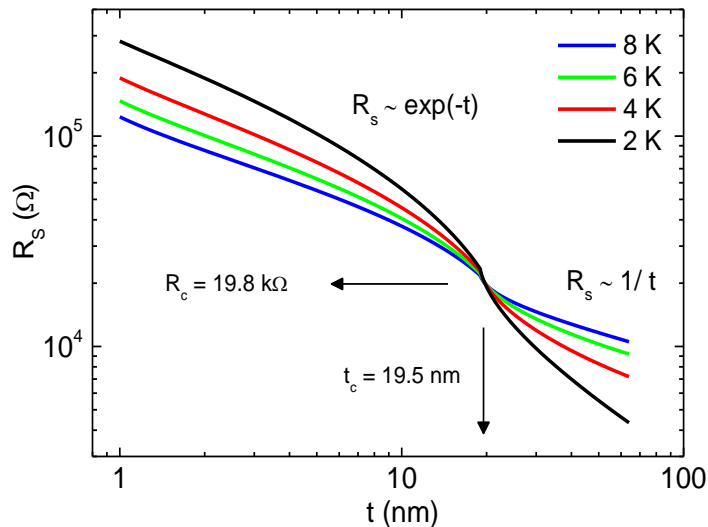
Disorder driven SIT



$$R_s = R_c f\left(\frac{|t - t_c|}{T^{1/z\nu}}\right)$$

z dynamical critical exponent
ν correlation-length exponent

$$\log \left| \frac{\partial R_s}{\partial t} \Big|_{t_c} \right| = -\frac{1}{z\nu} \log T + \text{const}$$



Boson localization

M.P.A. Fisher, Phys. Rev. Lett. **65**, 923 (1990)

- finite-size scaling of R_s
- linear log-log plot provides $z\nu$
- $z=1$: $\nu=7/3$ consistent with [universality class of quantum percolation](#)

Isotherms $R_s(t, T=\text{const.})$

- crossing point (t_c, R_c)
- strong exponential decrease of R_s with increasing t
- crossover to weak $1/t$ decrease

Quantum percolation

D.-H. Lee *et al.*, Phys. Rev. Lett. **70**, 4130 (1993)

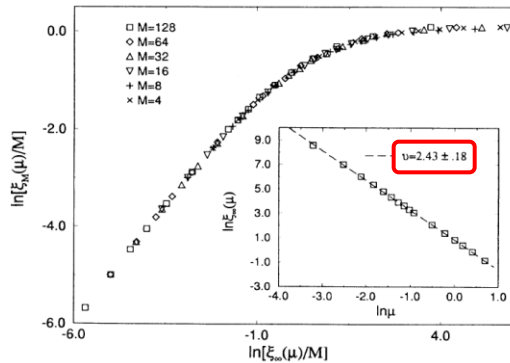
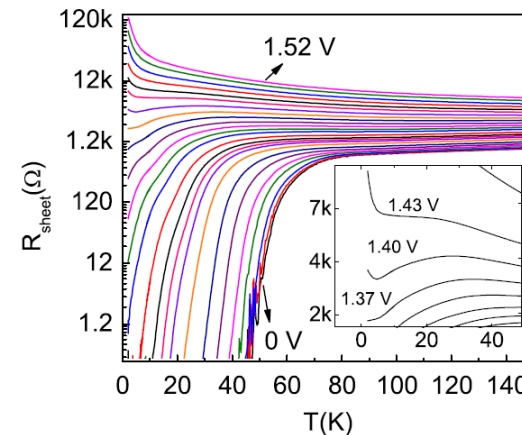


FIG. 3. The scaling plot for quantum percolation. Inset: $\ln E_{\infty}^{\nu}$ vs $\ln \mu$.

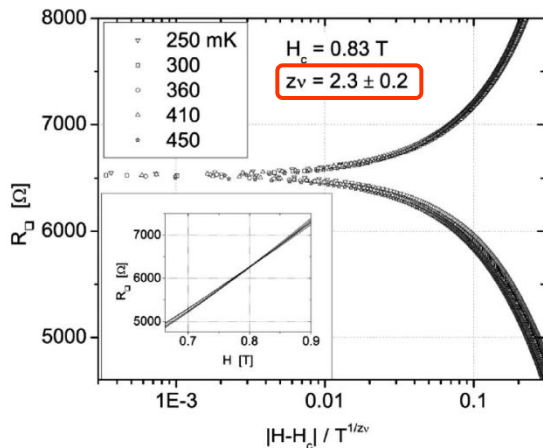
plateau transitions
in quantum Hall
liquids

X. Leng *et al.*, Phys. Rev. Lett. **107**, 027001 (2011)

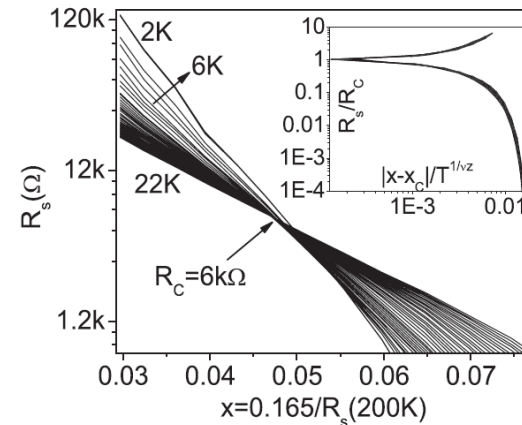
Ultrathin $\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ films



M.A. Steiner *et al.*, Phys. Rev. B **77**, 212501 (2008)

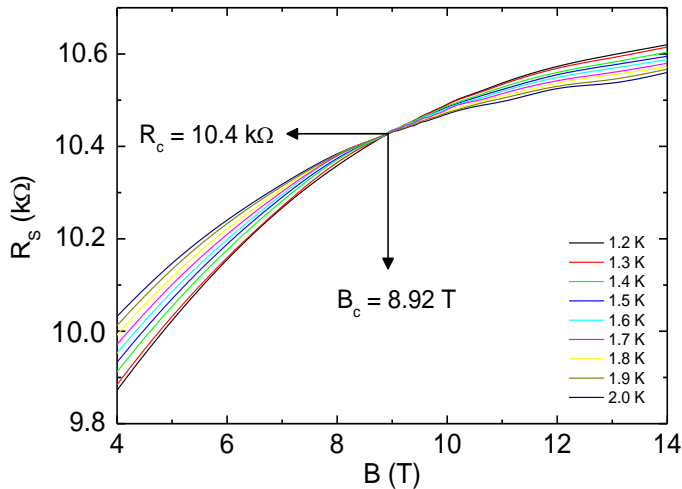
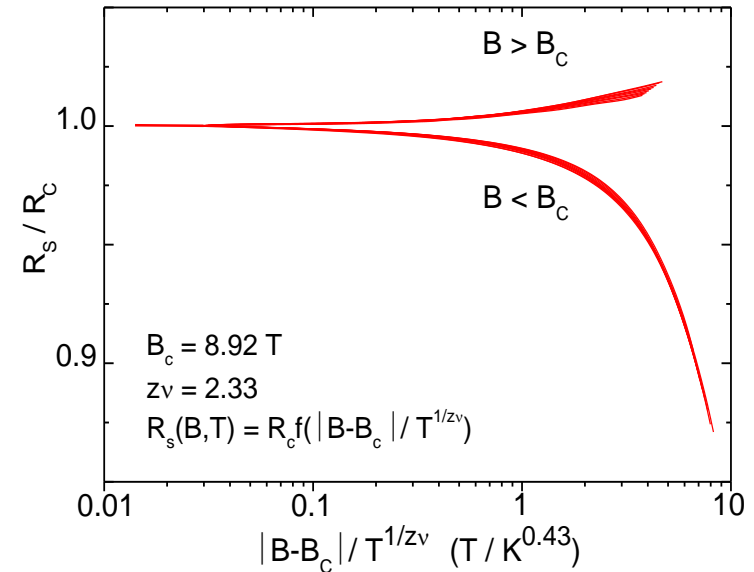
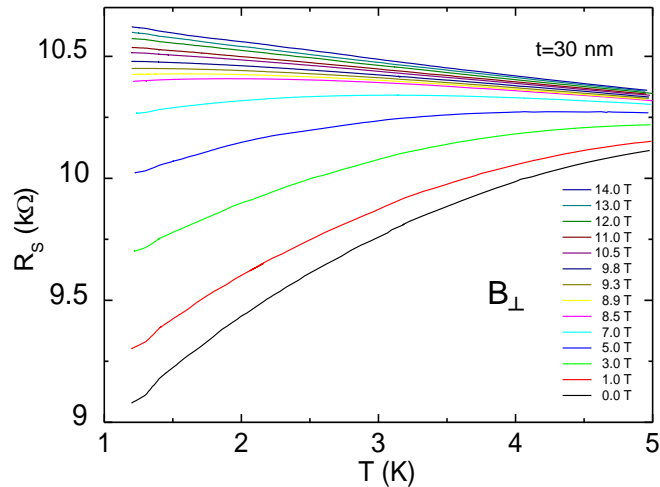


a-InO_x films



$z\nu = 2.2$

Magnetic-field induced SIT



Scaling of $R_s(B, T)$

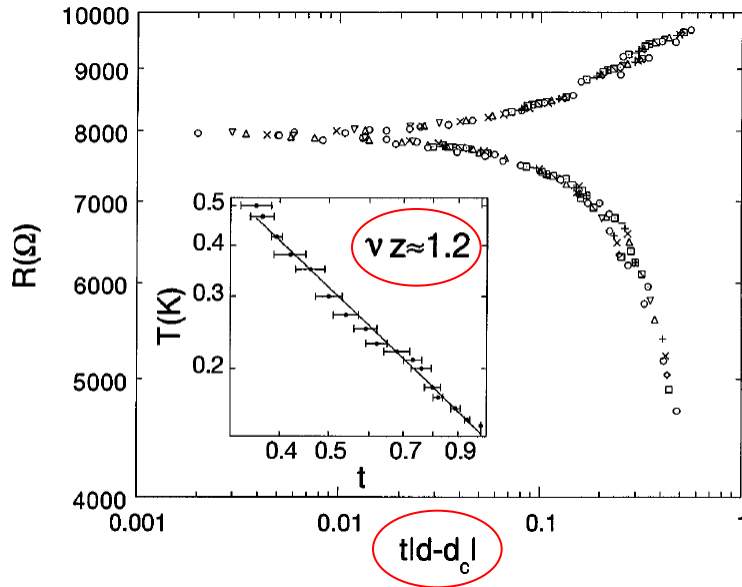
- collapse of the branches $B < B_c$ and $B > B_c$ onto a single curve
- scaling prediction of the Bose-glass model independently confirmed

Isotherms $R_s(B, T=\text{constant})$

- crossing point (B_c, R_c)
- no magnetoresistance peak below 14 T

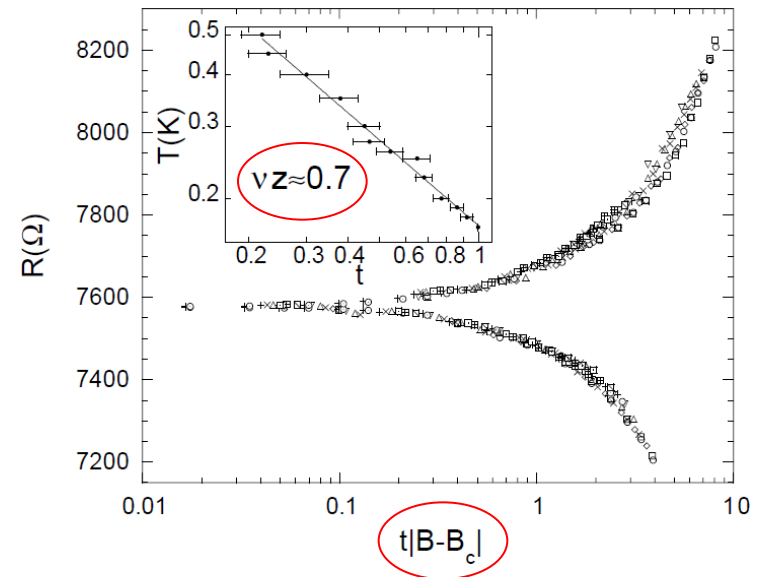
Different tuning parameters

N. Marković *et al.*, Phys. Rev. Lett. **81**, 5217 (1998)



- thickness d tuned SIT
- $\nu z \approx 1.2$
- universality class of classical percolation in 2D
- describes SIT in a 2D disordered system

a - Bi



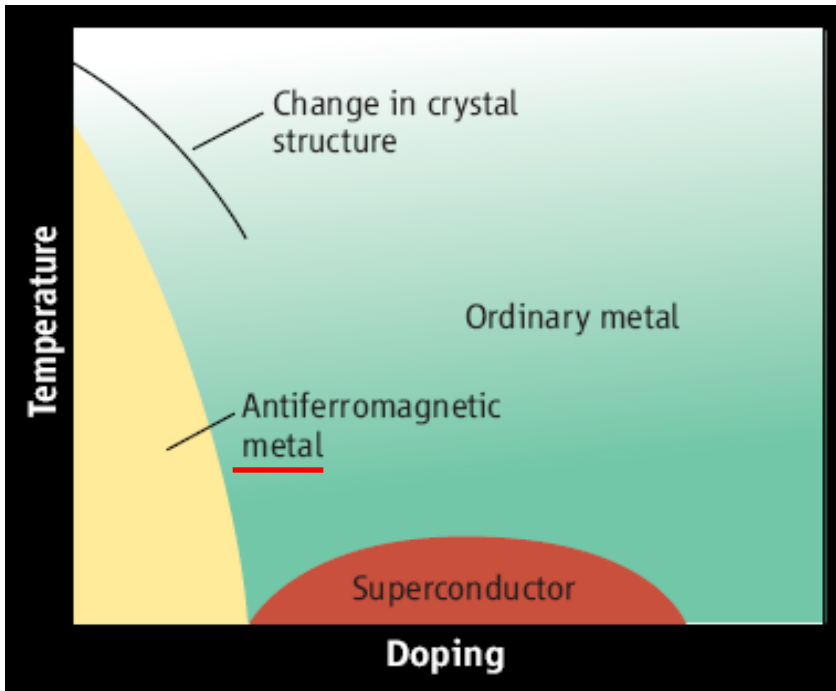
- magnetic field B tuned SIT
- $\nu z \approx 0.7$
- universality class of 3D XY model
- describes SIT in a 2D ordered system

Summary

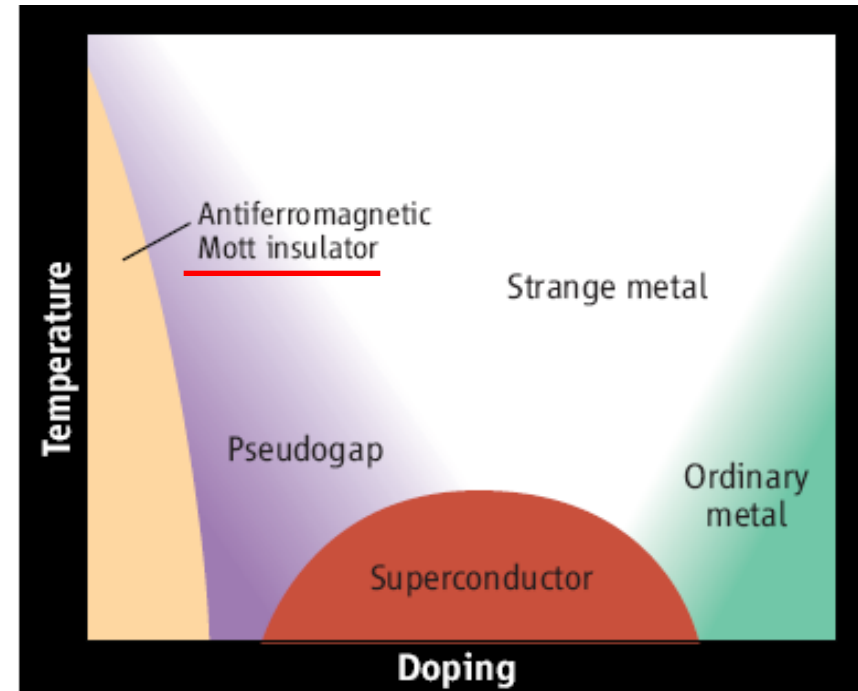
- reproducible synthesis of superconducting β -FeSe thin films by sputtering
- excess conductivity, BKT transition, large G_i
 - 2D character of superconductivity
 - importance of thermal fluctuations
- high sensitivity to disorder results in a thickness-driven SIT
- SIT also driven with magnetic field
- finite-size scaling according to the Bose-glass model
- universality class of quantum percolation

Temperature-doping phase diagrams

Magnetism and superconductivity

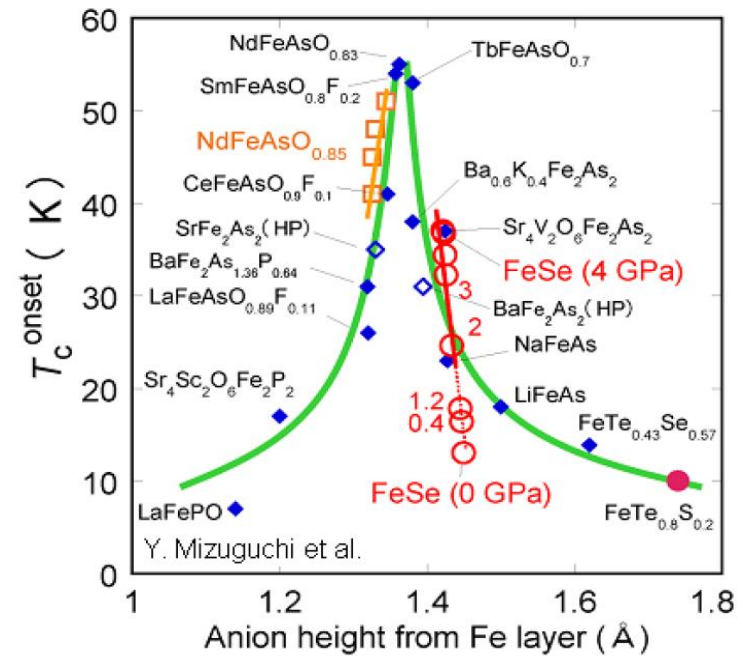
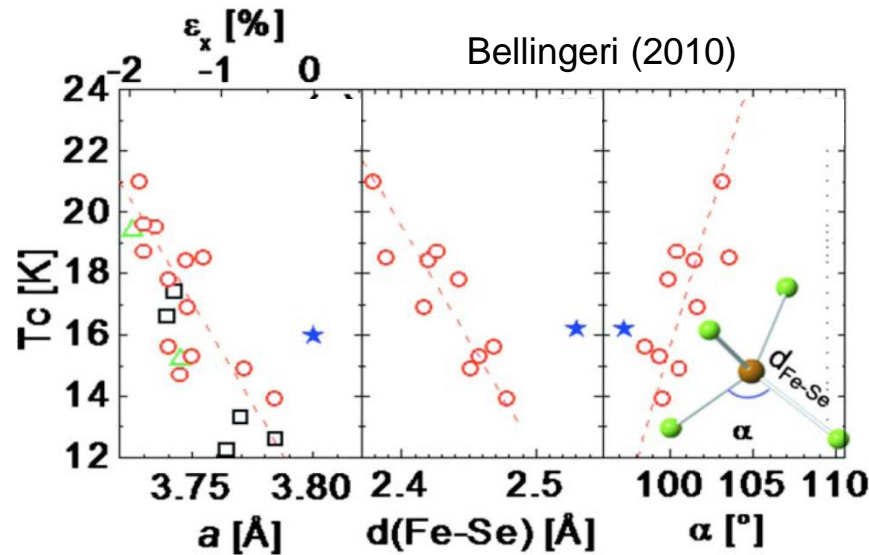
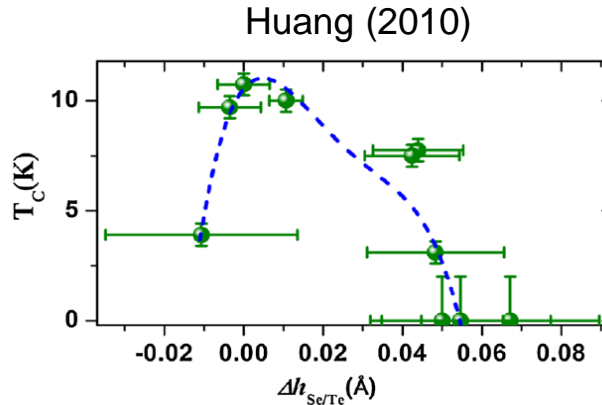
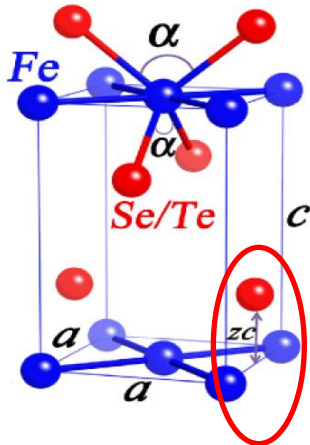


Fe-based superconductors

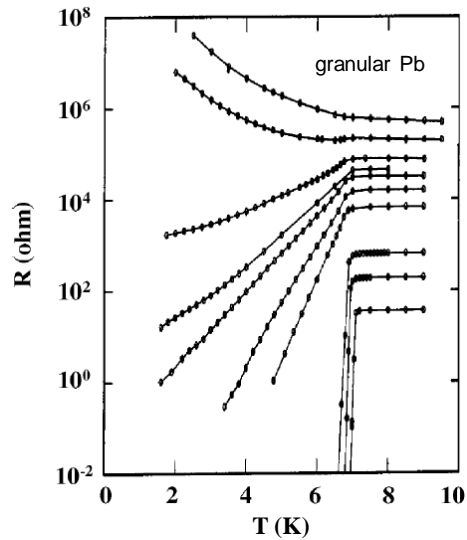
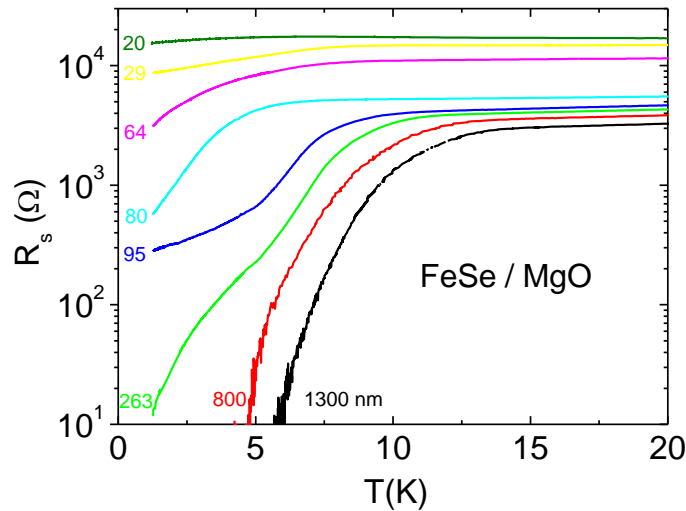


Cuprate superconductors

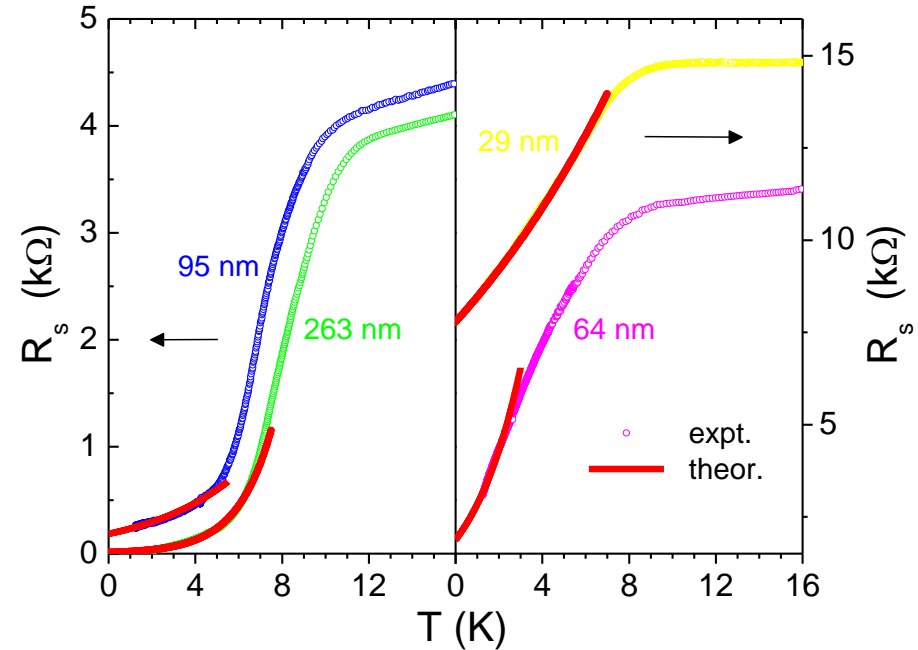
T_C and structural details



Resistance tails



A. Frydman, Physica C **391**,189 (2003)



- evolution of resistance tails
- described by „Inverse Arrhenius law“

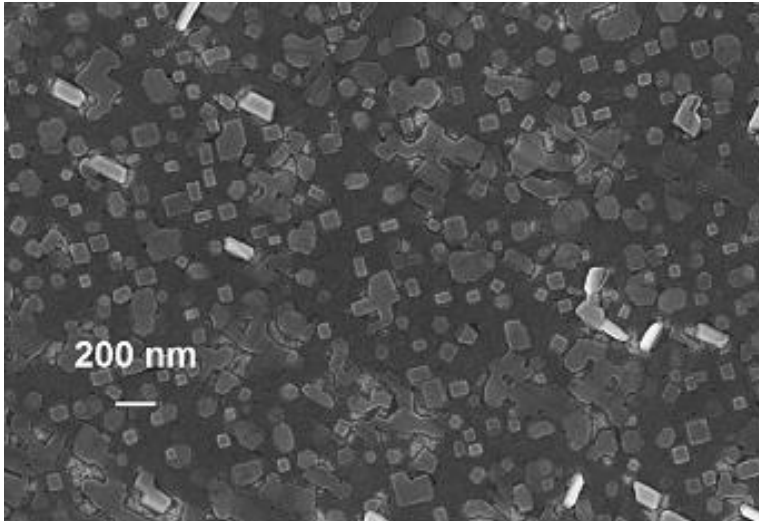
L. Merchant et al., Phys. Rev. B **63**, 134508 (2001)

$$R_s(T) = R_s(0) \exp\left(\frac{T}{T_0}\right)$$

- typical for granularity

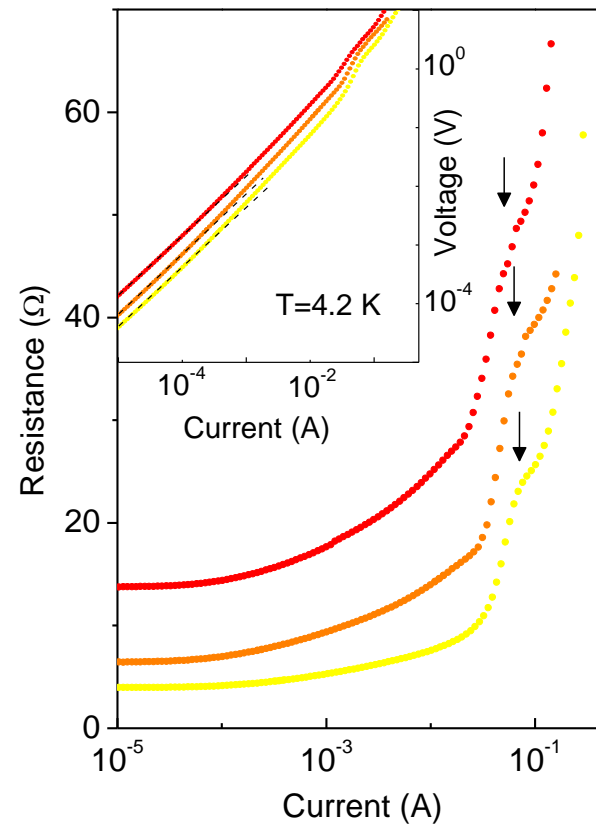
R. Schneider et al., Eur. Phys. J. B **88**, 14 (2015)

Granularity and weak links



- 20-nm-thick film at the edge of the superconducting phase
- individual crystallites
- structureless homogeneous matrix

- nonlinearities in the $V(I)$ characteristics
- current-dependent resistance $R=V/I$
- weak links with a broad distribution of low critical currents

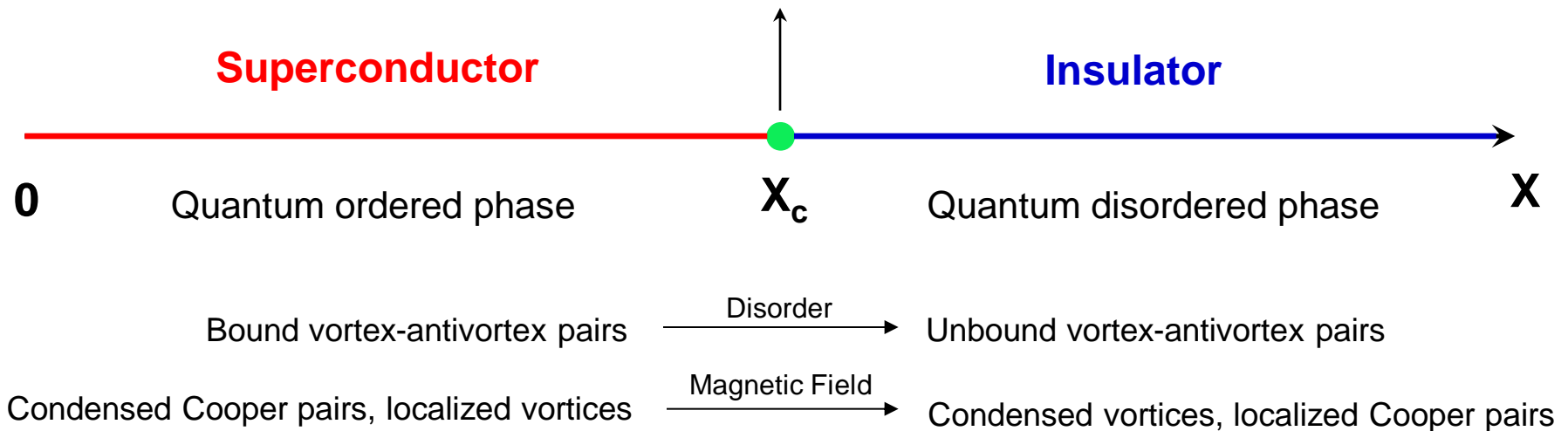


Theory of boson localization

Fisher (1990)

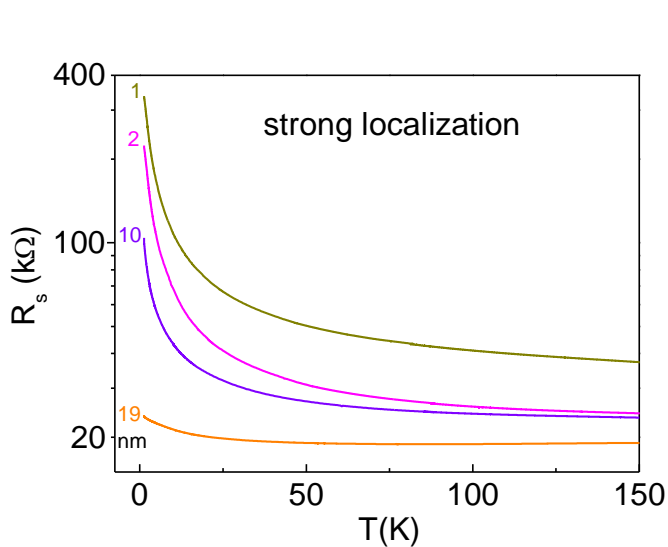
- predicts a **continuous SIT** at $T=0$ as a result of the interplay of the attractive electron-electron interaction and the long-range coulomb repulsion
- SIT is a **Quantum Phase Transition** (QPT): Transition at $T=0$ between competing ground states of a quantum system when a parameter x in the Hamiltonian crosses a critical value

Bose Metal with $R_c = R_q = h / (2e)^2$

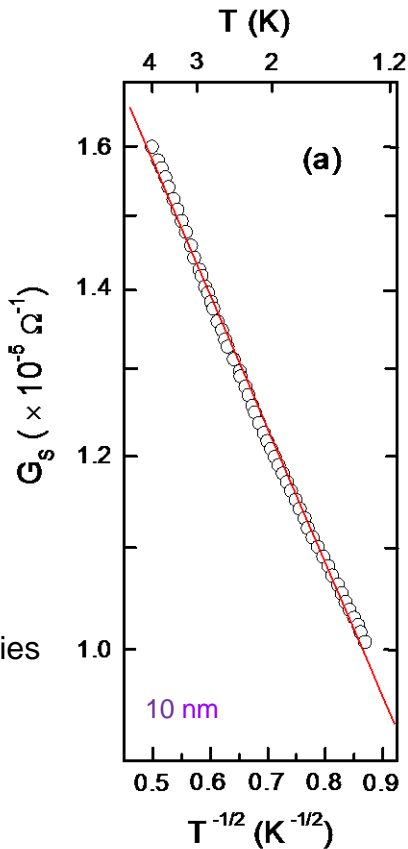


Value of the critical sheet resistance R_c is *universal* (independent of the material system and the microscopic details) and is equal to the *quantum resistance* R_q of electron pairs.

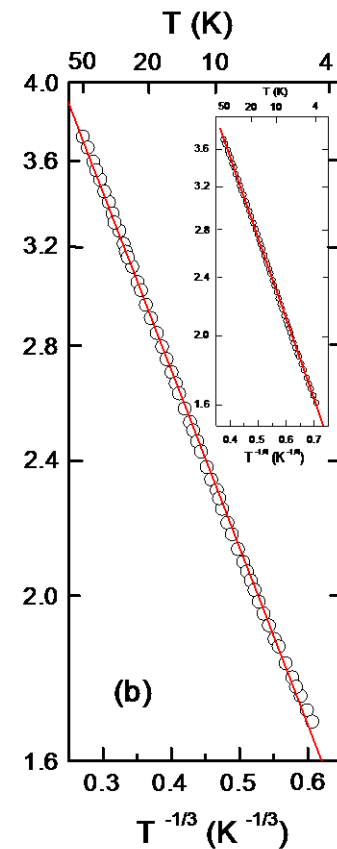
Insulating phase



sequence of exponential $G_s(T)$ dependencies



(a) $T < 4\text{K}$ Efros-Shklovskii VRH
A.L. Efros, B.I. Shklovskii, J. Phys. C **8**, L49 (1975)

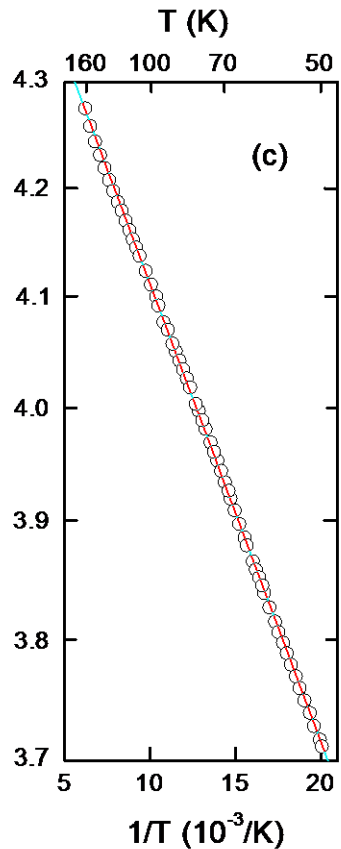


(b) $4\text{K} < T < 50\text{K}$ Mott VRH
N.F. Mott, J. Non-Cryst. Solids **1**, 1 (1968)

$$G_s = A_1 \exp\left(-\left(\frac{T_1}{T}\right)^{1/3}\right)$$

constant DOS

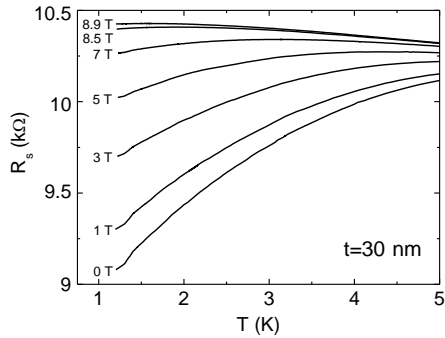
(c) $50\text{K} < T < 160\text{K}$ Arrhenius



$$G_s = A_2 \exp\left(-\frac{\Delta E_A}{k_B T}\right)$$

hard gap

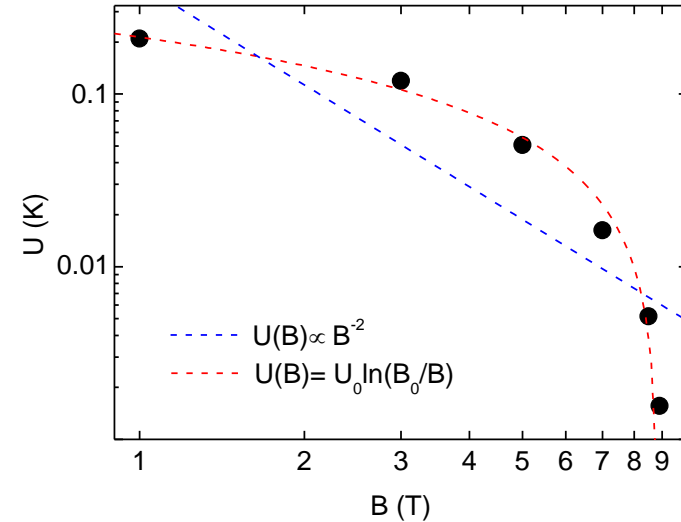
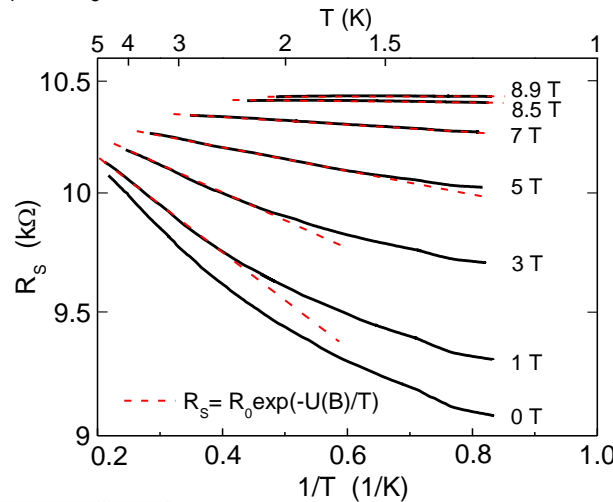
Superconducting phase in a magnetic field



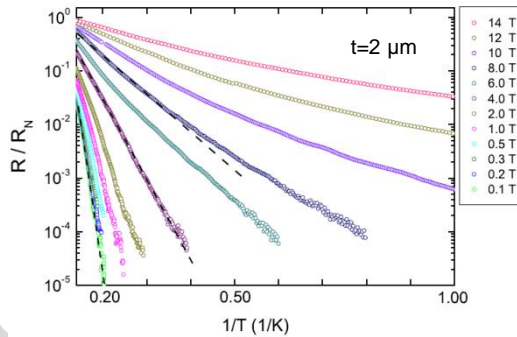
superconducting side of the B-SIT

$$R_s = R_0 e^{-\frac{U(B)}{T}}$$

P.H. Kes *et al.*,
Supercond. Sci. Technol.
1, 242 (1989)



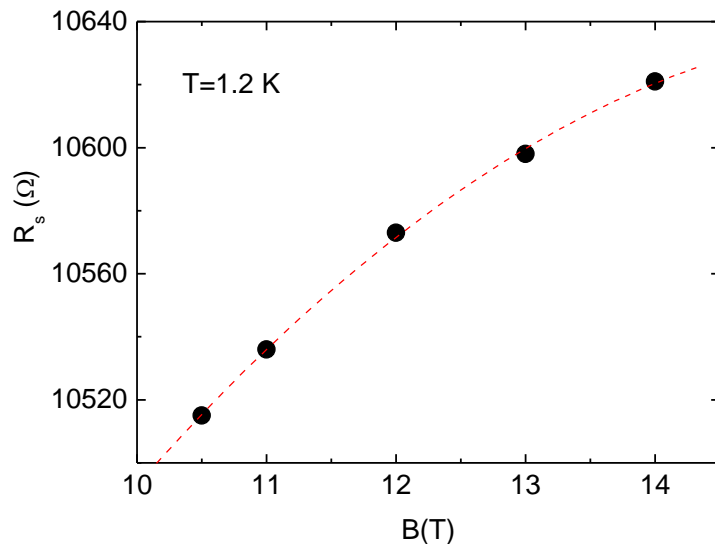
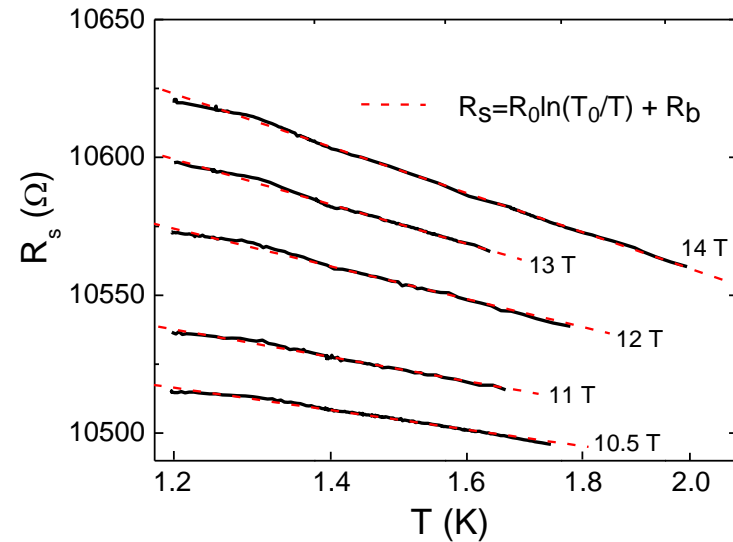
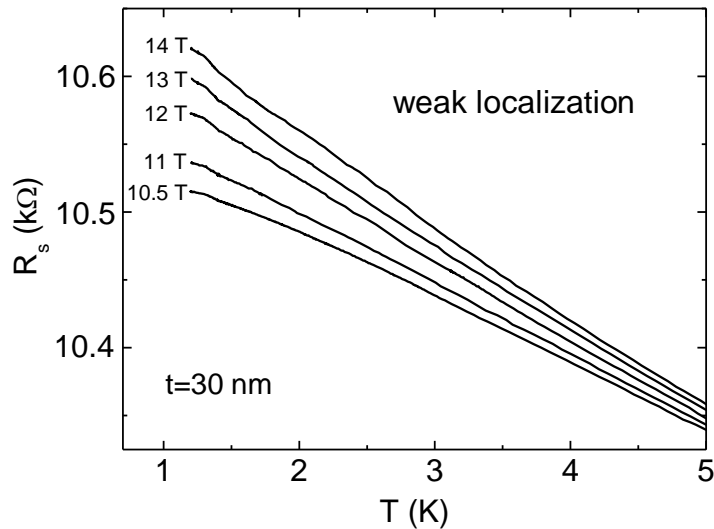
- logarithmic field dependence ($U_0=0.098$ K, $B_0=8.85$ T)
- possible creep-type dissipation mechanism
- small values of U, low pinning barriers
- power-law fit definitely fails



comparison with
„bulklike“ FeSe film

A.G. Zaitsev *et al.*,
J. Phys. Conf. Ser.
507, 012054 (2014)

Insulating phase in a magnetic field



$$R_s = R_0 \ln\left(\frac{T_0}{T}\right) + R_b$$

D. Das, S. Doniach, Phys. Rev. B **57**, 14440 (1998)

- weakly localized Cooper pairs (Bose glass)
- vortices in a quantum liquid phase
- crossover from \ln to $\exp T$ - dependence
- in line with bosonic description of SIT

R. Schneider *et al.*, J. Low Temp. Phys. **178**, 118 (2015)